

S11MD7T/S11MD8T/S11MD9T S21MD7T/S21MD8T/S21MD9T

* Taping reel type of **S21MD8T** is also available (**S21MD8P**)
 * DIN-VDE0884 approved type is also available.

■ Features

1. Low input driving current
(S11MD7T / S11MD8T / S21MD7T / S21MD8T)
 I_{FT} : MAX. 5mA
S11MD9T / S21MD9T I_{FT} : MAX.7mA)
2. Pin No. 5 completely molded for external noise resistance
3. Built-in zero-cross circuit (**S11MD8T/S21MD8T**)
4. High repetitive peak OFF-state voltage
(S11MD7T / S11MD8T / S11MD9T)
 V_{DRM} : MIN. 400V
S21MD7T / S21MD8T / S21MD9T
 V_{DRM} : MIN. 600V
5. Isolation voltage between input and output
 $(V_{iso} : 5\text{ }000\text{ V}_{rms})$
6. Recognized by UL, file No.E64380

■ Model Line-ups

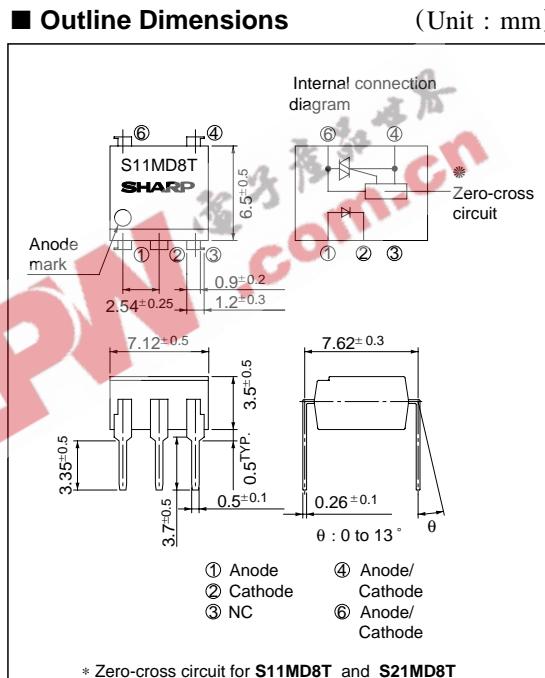
	100V line	200V line
No zero-cross circuit	S11MD7T/ S11MD9T	S21MD7T/ S21MD9T
Built-in zero-cross circuit	S11MD8T	S21MD8T

■ Applications

1. For triggering medium/high power triacs

■ Absolute Maximum Ratings

(Unit : mm)



Parameter	Symbol	Rating		Unit
		S11MD7T/S11MD8T S11MD9T	S21MD7T/S21MD8T/ S21MD9T	
Input	Forward current	I_F	50	mA
	Reverse voltage	V_R	6	V
Output	RMS ON-state current	I_T	0.1	A _{rms}
	* ¹ Park one cycle surge current	I_{surge}	1.2	A
	Repetitive peak OFF-state voltage	V_{DRM}	400	600
	* ² Isolation voltage	V_{iso}	5 000	V _{rms}
	Operating temperature	T_{opr}	-30 to +100	°C
	Storage temperature	T_{stg}	-55 to +125	°C
	* ³ Soldering temperature	T_{sol}	260	°C

*1 50Hz Sine wave

*2 40 to 60% RH, AC for 1 minute, f = 60Hz

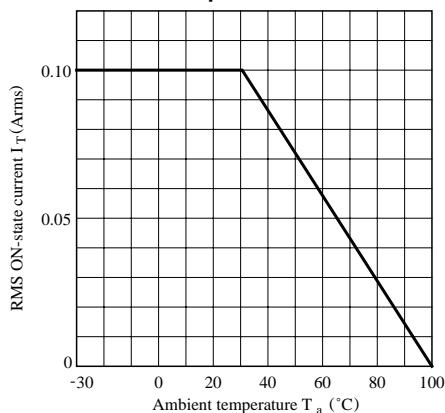
*3 For 10 seconds

SHARP**S11MD7T/S11MD8T/S11MD9T/S21MD7T/S21MD8T/S21MD9T****■ Electro-optical Characteristics**

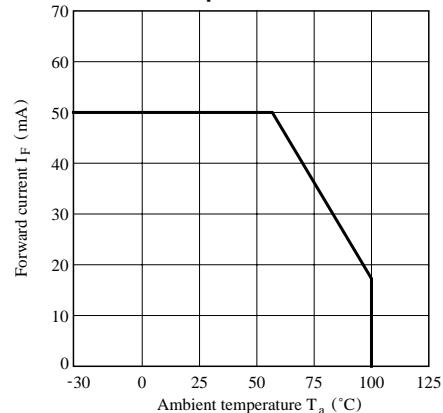
(Ta = 25°C)

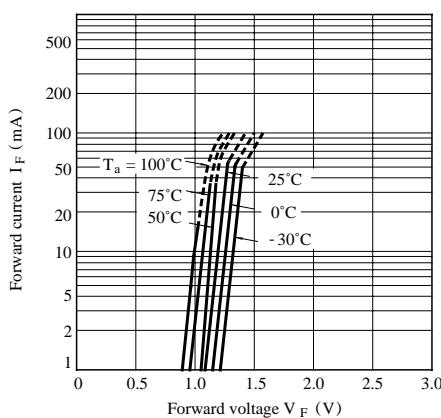
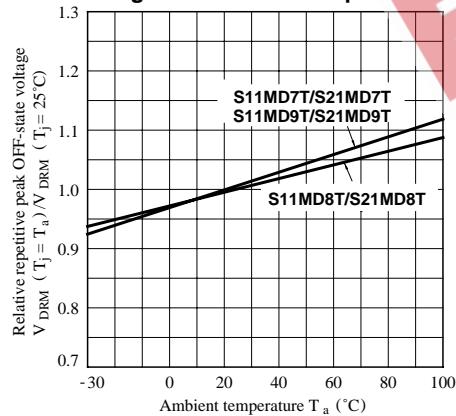
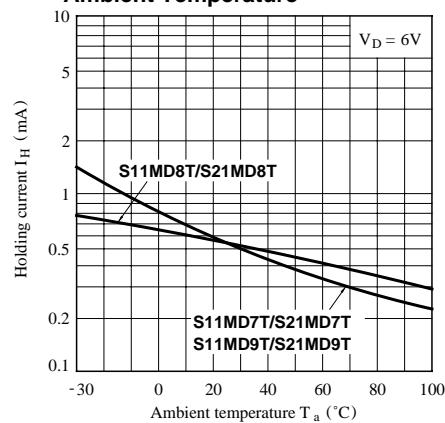
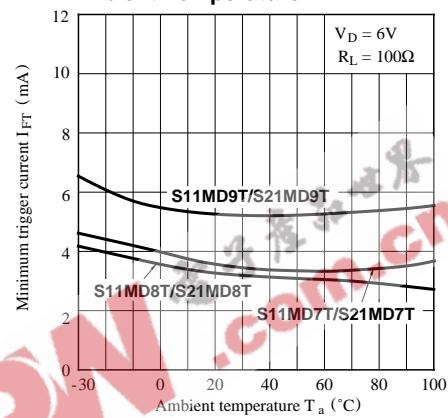
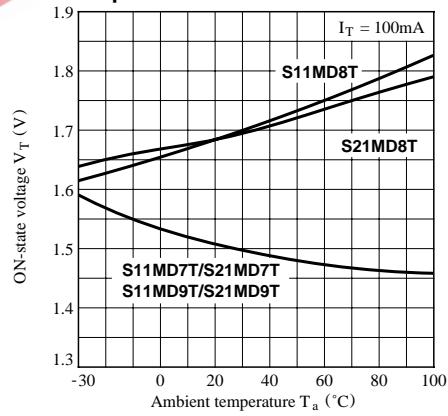
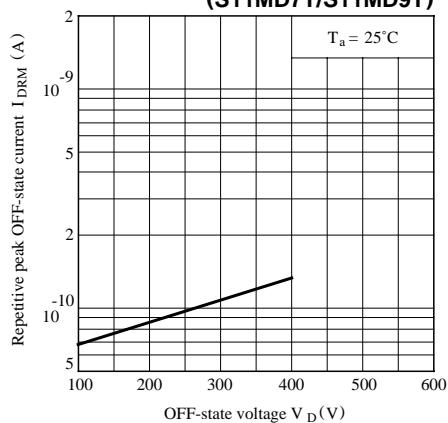
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 20mA	-	1.2	1.4	V
	Reverse current	I _R	V _R = 3V	-	-	10 ⁻⁵	A
Output	Repetitive peak OFF-state current	I _{DRM}	V _{DRM} = Rated	-	-	10 ⁻⁶	A
	ON-state voltage	V _T	I _T = 0.1A	-	1.5	2.5	V
	S11MD7T/S21MD7T S11MD9T/S21MD9T S11MD8T/S21MD8T			-	1.7	2.5	
	Holding current	I _H	V _D = 6V	0.1	0.5	3.5	mA
Transfer characteristics	Critical rate of rise of OFF-state voltage	dV/dt	V _{DRM} = 1/ $\sqrt{2}$ • Rated	100	-	-	V/ μ s
	Zere-cross voltage	V _{OX}	Resistance load, I _F = 10mA	-	-	35	V
	Minimum trigger current	I _{FT}	V _D = 6V, R _L = 100Ω	-	-	5	mA
	S11MD7T/S21MD7T S11MD8T/S21MD8T S11MD9T/S21MD9T			-	-	7	
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω
	Turn-on time	t _{on}	V _D = 6V, R _L = 100Ω I _F = 20mA	-	70	100	μs
	S11MD7T			-	60	100	
	S11MD9T/S21MD7T/ S21MD9T S11MD8T/S21MD8T			-	20	50	

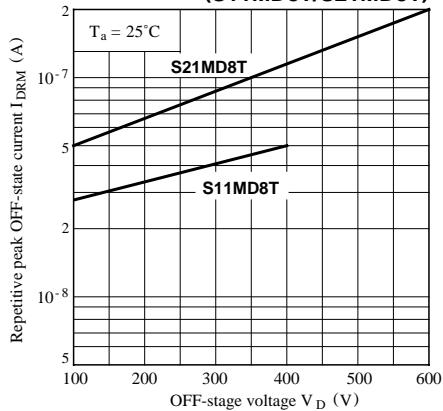
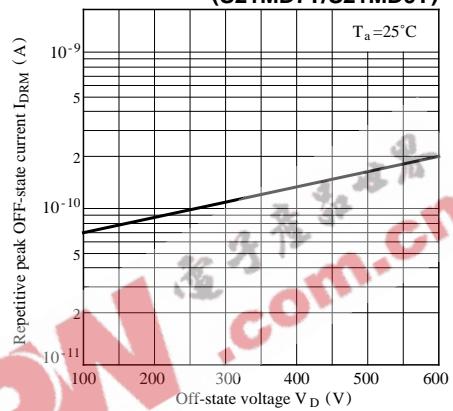
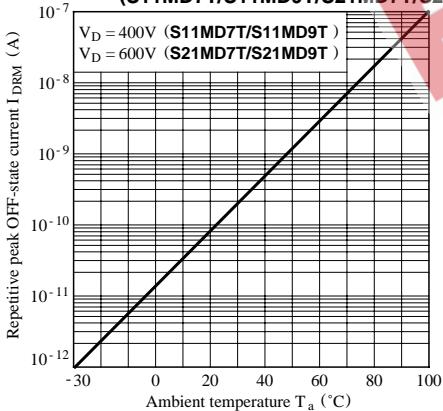
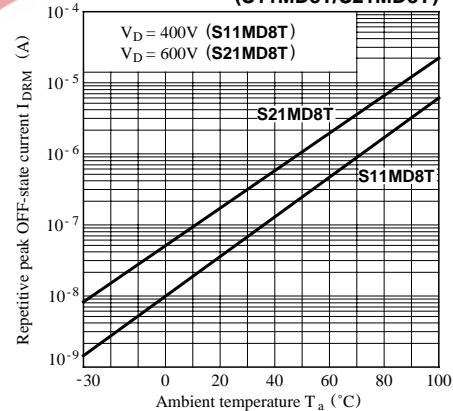
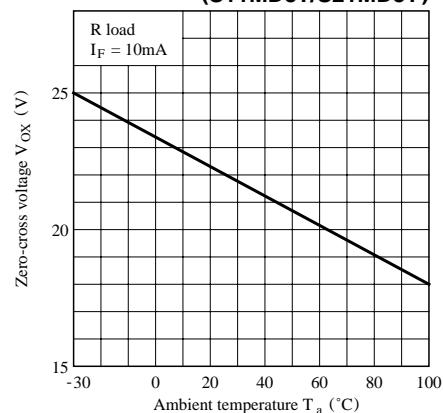
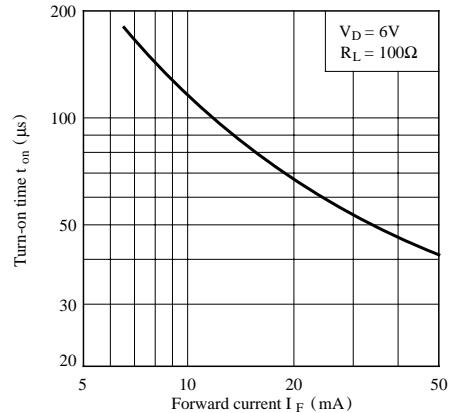
**Fig. 1 RMS ON-state Current vs.
Ambient Temperature**

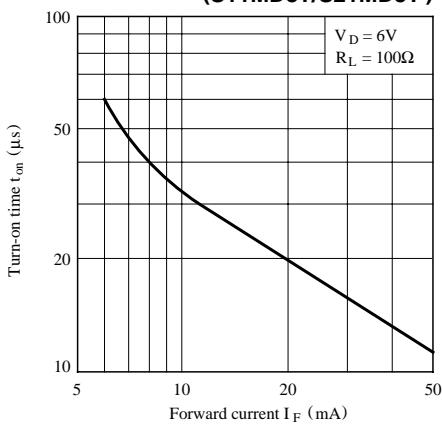
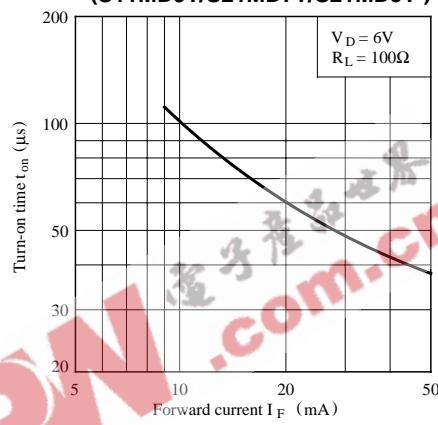
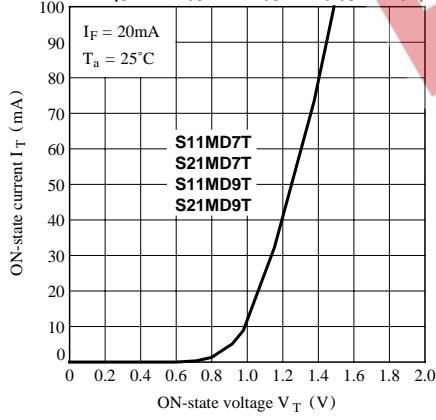
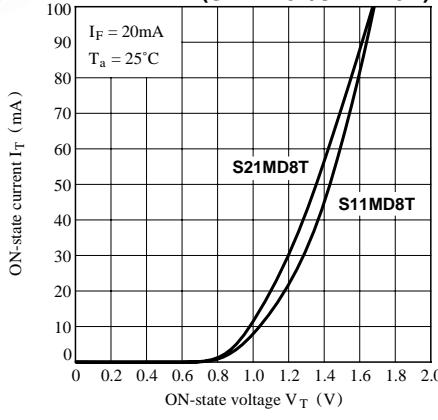
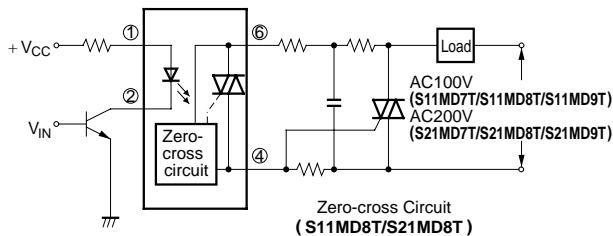


**Fig. 2 Forward Current vs.
Ambient Temperature**



SHARP**S11MD7T/S11MD8T/S11MD9T/S21MD7T/S21MD8T/S21MD9T****Fig. 3 Forward Current vs. Forward Voltage****Fig. 5 Relative Repetitive Peak OFF-State Voltage vs. Ambient Temperature****Fig. 7 Holding Current vs. Ambient Temperature****Fig. 4 Minimum Trigger Current vs. Ambient Temperature****Fig. 6 ON-state Voltage vs. Ambient Temperature****Fig. 8-a Repetitive Peak OFF-state Current vs. OFF-state Voltage (S11MD7T/S11MD9T)**

SHARP**S11MD7T/S11MD8T/S11MD9T/S21MD7T/S21MD8T/S21MD9T****Fig. 8-b Repetitive Peak OFF-state Current vs. OFF-state Voltage (S11MD8T/S21MD8T)****Fig. 8-c Repetitive Peak OFF-state Current vs. OFF-state Voltage (S21MD7T/S21MD9T)****Fig. 9-a Repetitive Peak OFF-state Current vs. Ambient Temperature (S11MD7T/S11MD9T/S21MD7T/S21MD9T)****Fig. 9-b Repetitive Peak OFF-state Current vs. Ambient Temperature (S11MD8T/S21MD8T)****Fig.10 Zero-cross Voltage vs. Ambient Temperature (S11MD8T/S21MD8T)****Fig.11-a Turn-on Time vs. Forward Current (S11MD7T)**

SHARP**S11MD7T/S11MD8T/S11MD9T/S21MD7T/S21MD8T/S21MD9T****Fig.11-b Turn-on Time vs. Forward Current
(S11MD8T/S21MD8T)****Fig.11-c Turn-on Time vs. Forward Current
(S11MD9T/S21MD7T/S21MD9T)****Fig.12-a ON-state Current vs.
ON-state Voltage
(S11MD7T/S21MD7T/S11MD9T/S21MD9T)****Fig.12-b ON-state Current vs.
ON-state Voltage
(S11MD8T/S21MD8T)****■ Basic Operation Circuit****S11MD7T/S11MD8T/S11MD9T
S21MD7T/S21MD8T/S21MD9T**

- Please refer to the chapter "Precautions for Use."